

# CD54HC243, CD74HC243, CD54HCT243, CD74HCT243

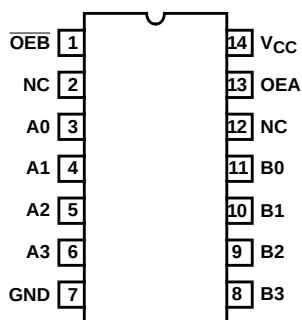
## High-Speed CMOS Logic Quad-Bus Transceiver with Three-State Outputs

### Features

- Typical Propagation Delay (A to B, B to A) of 7ns at  $V_{CC} = 5V$ ,  $C_L = 15pF$ ,  $T_A = 25^{\circ}C$
- Three-State Outputs
- Buffered Inputs
- Fanout (Over Temperature Range)
  - Standard Outputs . . . . . 10 LSTTL Loads
  - Bus Driver Outputs . . . . . 15 LSTTL Loads
- Wide Operating Temperature Range . . .  $-55^{\circ}C$  to  $125^{\circ}C$
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL} = 30\%$ ,  $N_{IH} = 30\%$  of  $V_{CC}$  at  $V_{CC} = 5V$
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,  $V_{IL} = 0.8V$  (Max),  $V_{IH} = 2V$  (Min)
  - CMOS Input Compatibility,  $I_I \leq 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

### Pinout

CD54HC243, CD54HCT243  
(CERDIP)  
CD74HC243, CD74HCT243  
(PDIP, SOIC)  
TOP VIEW



### Description

The 'HC243 and 'HCT243 silicon-gate CMOS three-state bidirectional noninverting buffers are intended for two-way asynchronous communication between data buses. They have high-drive-current outputs that enable high-speed operation when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuits and have speeds comparable to low-power Schottky TTL circuits. They can drive 15 LSTTL loads.

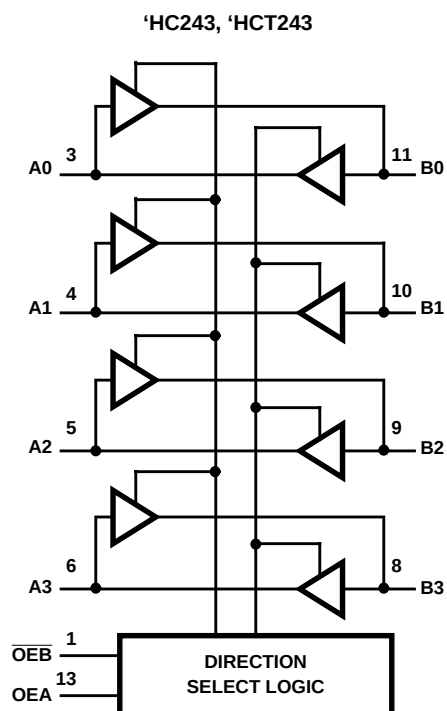
The states of the output-enable ( $\overline{OEB}$ , OEA) inputs determine both the direction of flow (A to B, B to A), and the three-state mode.

### Ordering Information

| PART NUMBER   | TEMP. RANGE<br>( $^{\circ}C$ ) | PACKAGE      |
|---------------|--------------------------------|--------------|
| CD54HC243F3A  | -55 to 125                     | 14 Ld CERDIP |
| CD54HCT243F3A | -55 to 125                     | 14 Ld CERDIP |
| CD74HC243E    | -55 to 125                     | 14 Ld PDIP   |
| CD74HC243M    | -55 to 125                     | 14 Ld SOIC   |
| CD74HC243MT   | -55 to 125                     | 14 Ld SOIC   |
| CD74HC243M96  | -55 to 125                     | 14 Ld SOIC   |
| CD74HCT243E   | -55 to 125                     | 14 Ld PDIP   |
| CD74HCT243M   | -55 to 125                     | 14 Ld SOIC   |

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

## Functional Diagram



TRUTH TABLE

| CONTROL INPUTS          |     | HC, HCT243 SERIES |    |
|-------------------------|-----|-------------------|----|
|                         |     | DATA PORT STATUS  |    |
| $\overline{\text{OEB}}$ | OEA | An                | Bn |
| H                       | H   | O                 | I  |
| L                       | H   | Z                 | Z  |
| H                       | L   | Z                 | Z  |
| L                       | L   | I                 | O  |

H= High Voltage Level

L= Low Voltage Level

I= Input

O= Output (Same Level as Input)

Z= High Impedance

To prevent excess currents in the High Z modes all I/O terminals should be terminated with 10k $\Omega$  to 1M $\Omega$  resistors.

# CD54HC243, CD74HC243, CD54HCT243, CD74HCT243

## Absolute Maximum Ratings

|                                                        |             |
|--------------------------------------------------------|-------------|
| DC Supply Voltage, $V_{CC}$                            | -0.5V to 7V |
| DC Input Diode Current, $I_{IK}$                       |             |
| For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$             | $\pm 20mA$  |
| DC Output Diode Current, $I_{OK}$                      |             |
| For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$             | $\pm 20mA$  |
| DC Drain Current, per Output, $I_O$                    |             |
| For $-0.5V < V_O < V_{CC} + 0.5V$                      | $\pm 35mA$  |
| DC Output Source or Sink Current per Output Pin, $I_O$ |             |
| For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$             | $\pm 25mA$  |
| DC $V_{CC}$ or Ground Current, $I_{CC}$                | $\pm 70mA$  |

## Thermal Information

|                                          |                                    |
|------------------------------------------|------------------------------------|
| Thermal Resistance (Typical, Note 1)     | $\theta_{JA}$ ( $^{\circ}C/W$ )    |
| E (PDIP) Package                         | 80                                 |
| M (SOIC) Package                         | 86                                 |
| Maximum Junction Temperature             | 150 $^{\circ}C$                    |
| Maximum Storage Temperature Range        | -65 $^{\circ}C$ to 150 $^{\circ}C$ |
| Maximum Lead Temperature (Soldering 10s) | 300 $^{\circ}C$                    |
| (SOIC - Lead Tips Only)                  |                                    |

## Operating Conditions

|                                           |                                    |
|-------------------------------------------|------------------------------------|
| Temperature Range ( $T_A$ )               | -55 $^{\circ}C$ to 125 $^{\circ}C$ |
| Supply Voltage Range, $V_{CC}$            |                                    |
| HC Types                                  | .2V to 6V                          |
| HCT Types                                 | .4.5V to 5.5V                      |
| DC Input or Output Voltage, $V_I$ , $V_O$ | 0V to $V_{CC}$                     |
| Input Rise and Fall Time                  |                                    |
| 2V                                        | 1000ns (Max)                       |
| 4.5V                                      | 500ns (Max)                        |
| 6V                                        | 400ns (Max)                        |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## DC Electrical Specifications

| PARAMETER                               | SYMBOL          | TEST CONDITIONS                       |                     | V <sub>CC</sub> (V) | 25°C |     |      | -40°C TO 85°C |      | -55°C TO 125°C |      | UNITS |
|-----------------------------------------|-----------------|---------------------------------------|---------------------|---------------------|------|-----|------|---------------|------|----------------|------|-------|
|                                         |                 | V <sub>I</sub> (V)                    | I <sub>O</sub> (mA) |                     | MIN  | TYP | MAX  | MIN           | MAX  | MIN            | MAX  |       |
| HC TYPES                                |                 |                                       |                     |                     |      |     |      |               |      |                |      |       |
| High Level Input Voltage                | V <sub>IH</sub> | -                                     | -                   | 2                   | 1.5  | -   | -    | 1.5           | -    | 1.5            | -    | V     |
|                                         |                 |                                       |                     | 4.5                 | 3.15 | -   | -    | 3.15          | -    | 3.15           | -    | V     |
|                                         |                 |                                       |                     | 6                   | 4.2  | -   | -    | 4.2           | -    | 4.2            | -    | V     |
| Low Level Input Voltage                 | V <sub>IL</sub> | -                                     | -                   | 2                   | -    | -   | 0.5  | -             | 0.5  | -              | 0.5  | V     |
|                                         |                 |                                       |                     | 4.5                 | -    | -   | 1.35 | -             | 1.35 | -              | 1.35 | V     |
|                                         |                 |                                       |                     | 6                   | -    | -   | 1.8  | -             | 1.8  | -              | 1.8  | V     |
| High Level Output Voltage<br>CMOS Loads | V <sub>OH</sub> | V <sub>IH</sub> or<br>V <sub>IL</sub> | -0.02               | 2                   | 1.9  | -   | -    | 1.9           | -    | 1.9            | -    | V     |
|                                         |                 |                                       | -0.02               | 4.5                 | 4.4  | -   | -    | 4.4           | -    | 4.4            | -    | V     |
|                                         |                 |                                       | -0.02               | 6                   | 5.9  | -   | -    | 5.9           | -    | 5.9            | -    | V     |
| High Level Output Voltage<br>TTL Loads  |                 |                                       | -6                  | 4.5                 | 3.98 | -   | -    | 3.84          | -    | 3.7            | -    | V     |
| -7.8                                    |                 |                                       | 6                   | 5.48                | -    | -   | 5.34 | -             | 5.2  | -              | V    |       |
| Low Level Output Voltage<br>CMOS Loads  | V <sub>OL</sub> | V <sub>IH</sub> or<br>V <sub>IL</sub> | 0.02                | 2                   | -    | -   | 0.1  | -             | 0.1  | -              | 0.1  | V     |
|                                         |                 |                                       | 0.02                | 4.5                 | -    | -   | 0.1  | -             | 0.1  | -              | 0.1  | V     |
|                                         |                 |                                       | 0.02                | 6                   | -    | -   | 0.1  | -             | 0.1  | -              | 0.1  | V     |
| Low Level Output Voltage<br>TTL Loads   |                 |                                       | 6                   | 4.5                 | -    | -   | 0.26 | -             | 0.33 | -              | 0.4  | V     |
|                                         |                 |                                       | 7.8                 | 6                   | -    | -   | 0.26 | -             | 0.33 | -              | 0.4  | V     |

**CD54HC243, CD74HC243, CD54HCT243, CD74HCT243**

**DC Electrical Specifications** (Continued)

| PARAMETER                                                      | SYMBOL                    | TEST CONDITIONS                    |                     | V <sub>CC</sub> (V) | 25°C |     |      | -40°C TO 85°C |      | -55°C TO 125°C |     | UNITS |
|----------------------------------------------------------------|---------------------------|------------------------------------|---------------------|---------------------|------|-----|------|---------------|------|----------------|-----|-------|
|                                                                |                           | V <sub>I</sub> (V)                 | I <sub>O</sub> (mA) |                     | MIN  | TYP | MAX  | MIN           | MAX  | MIN            | MAX |       |
| Input Leakage Current                                          | I <sub>I</sub>            | V <sub>CC</sub> or GND             | -                   | 6                   | -    | -   | ±0.1 | -             | ±1   | -              | ±1  | μA    |
| Quiescent Device Current                                       | I <sub>CC</sub>           | V <sub>CC</sub> or GND             | 0                   | 6                   | -    | -   | 8    | -             | 80   | -              | 160 | μA    |
| Three-State Leakage Current                                    | I <sub>OZ</sub>           | V <sub>IL</sub> or V <sub>IH</sub> | -                   | 6                   | -    | -   | ±0.5 | -             | ±0.5 | -              | ±10 | μA    |
| <b>HCT TYPES</b>                                               |                           |                                    |                     |                     |      |     |      |               |      |                |     |       |
| High Level Input Voltage                                       | V <sub>IH</sub>           | -                                  | -                   | 4.5 to 5.5          | 2    | -   | -    | 2             | -    | 2              | -   | V     |
| Low Level Input Voltage                                        | V <sub>IL</sub>           | -                                  | -                   | 4.5 to 5.5          | -    | -   | 0.8  | -             | 0.8  | -              | 0.8 | V     |
| High Level Output Voltage<br>CMOS Loads                        | V <sub>OH</sub>           | V <sub>IH</sub> or V <sub>IL</sub> | -0.02               | 4.5                 | 4.4  | -   | -    | 4.4           | -    | 4.4            | -   | V     |
| High Level Output Voltage<br>TTL Loads                         |                           |                                    | -6                  | 4.5                 | 3.98 | -   | -    | 3.84          | -    | 3.7            | -   | V     |
| Low Level Output Voltage<br>CMOS Loads                         | V <sub>OL</sub>           | V <sub>IH</sub> or V <sub>IL</sub> | 0.02                | 4.5                 | -    | -   | 0.1  | -             | 0.1  | -              | 0.1 | V     |
| Low Level Output Voltage<br>TTL Loads                          |                           |                                    | 6                   | 4.5                 | -    | -   | 0.26 | -             | 0.33 | -              | 0.4 | V     |
| Input Leakage Current                                          | I <sub>I</sub>            | V <sub>CC</sub> to GND             | -                   | 5.5                 | -    | -   | ±0.1 | -             | ±1   | -              | ±1  | μA    |
| Quiescent Device Current                                       | I <sub>CC</sub>           | V <sub>CC</sub> or GND             | 0                   | 5.5                 | -    | -   | 8    | -             | 80   | -              | 160 | μA    |
| Additional Quiescent Device Current Per Input Pin: 1 Unit Load | ΔI <sub>CC</sub> (Note 2) | V <sub>CC</sub> -2.1               | -                   | 4.5 to 5.5          | -    | 100 | 360  | -             | 450  | -              | 490 | μA    |
| Three-State Leakage Current                                    | I <sub>OZ</sub>           | V <sub>IL</sub> or V <sub>IH</sub> | -                   | 5.5                 | -    | -   | ±0.5 | -             | ±5.0 | -              | ±10 | μA    |

NOTE:

- For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

**HCT Input Loading Table**

| INPUT                        | UNIT LOADS |
|------------------------------|------------|
| An, Bn                       | 1.1        |
| OEA, $\overline{\text{OEB}}$ | 0.6        |

NOTE: Unit Load is ΔI<sub>CC</sub> limit specified in DC Electrical Specifications table, e.g., 360μA max at 25°C.

# **CD54HC243, CD74HC243, CD54HCT243, CD74HCT243**

## **Switching Specifications** Input $t_r, t_f = 6\text{ns}$

| PARAMETER                                     | SYMBOL                              | TEST CONDITIONS       | V <sub>CC</sub> (V) | 25°C |     | -40°C TO 85°C | -55°C TO 125°C | UNITS |
|-----------------------------------------------|-------------------------------------|-----------------------|---------------------|------|-----|---------------|----------------|-------|
|                                               |                                     |                       |                     | TYP  | MAX | MAX           | MAX            |       |
| HC TYPES                                      |                                     |                       |                     |      |     |               |                |       |
| Propagation Delay Data to Outputs             | t <sub>PLH</sub> , t <sub>PHL</sub> | C <sub>L</sub> = 50pF | 2                   | -    | 90  | 115           | 135            | ns    |
|                                               |                                     |                       | 4.5                 | -    | 18  | 23            | 27             | ns    |
|                                               |                                     | C <sub>L</sub> = 15pF | 5                   | 7    | -   | -             | -              | ns    |
|                                               |                                     | CL = 50pF             | 6                   | -    | 15  | 20            | 23             | ns    |
| Output High-Z, to High Level to Low Level     | t <sub>PZL</sub> , t <sub>PZH</sub> | C <sub>L</sub> = 50pF | 2                   | -    | 150 | 190           | 225            | ns    |
|                                               |                                     | CL = 50pF             | 4.5                 | -    | 30  | 38            | 45             | ns    |
|                                               |                                     | CL = 15pF             | 5                   | 12   | -   | -             | -              | ns    |
|                                               |                                     | CL = 50pF             | 6                   | -    | 26  | 33            | 38             | ns    |
| Output High Level, Output Low Level to High-Z | t <sub>PHZ</sub> , t <sub>PLZ</sub> | C <sub>L</sub> = 50pF | 2                   | -    | 150 | 190           | 225            | ns    |
|                                               |                                     | CL = 50pF             | 4.5                 | -    | 30  | 38            | 45             | ns    |
|                                               |                                     | CL = 15pF             | 5                   | 12   | -   | -             | -              | ns    |
|                                               |                                     | CL = 50pF             | 6                   | -    | 26  | 33            | 38             | ns    |
| Output Transition Times                       | t <sub>TLH</sub> , t <sub>THL</sub> | C <sub>L</sub> = 50pF | 2                   | -    | 60  | 75            | 90             | ns    |
|                                               |                                     |                       | 4.5                 | -    | 12  | 15            | 18             | ns    |
|                                               |                                     |                       | 6                   | -    | 10  | 13            | 15             | ns    |
| Input Capacitance                             | C <sub>I</sub>                      | -                     | -                   | -    | 10  | 10            | 10             | pF    |
| Three-State Output Capacitance                | C <sub>O</sub>                      | -                     | -                   | -    | 20  | 20            | 20             | pF    |
| Power Dissipation Capacitance (Notes 3, 4)    | C <sub>PD</sub>                     | -                     | 5                   | 80   | -   | -             | -              | pF    |
| HCT TYPES                                     |                                     |                       |                     |      |     |               |                |       |
| Propagation Delay Data to Outputs             | t <sub>PLH</sub> , t <sub>PHL</sub> | C <sub>L</sub> = 50pF | 4.5                 | -    | 22  | 28            | 33             | ns    |
|                                               |                                     | C <sub>L</sub> = 15pF | 5                   | 9    | -   | -             | -              | ns    |
| Output High-Z to High Level to Low Level      | t <sub>PZH</sub> , t <sub>PZL</sub> | C <sub>L</sub> = 50pF | 4.5                 | -    | 34  | 43            | 51             | ns    |
|                                               |                                     | C <sub>L</sub> = 15pF | 5                   | 14   | -   | -             | -              | ns    |
| Output High Level, Output Low Level to High-Z | t <sub>PHZ</sub> , t <sub>PLZ</sub> | C <sub>L</sub> = 50pF | 4.5                 | -    | 35  | 44            | 53             | ns    |
|                                               |                                     | C <sub>L</sub> = 15pF | 5                   | 14   | -   | -             | -              | ns    |
| Output Transition Times                       | t <sub>TLH</sub> , t <sub>THL</sub> | C <sub>L</sub> = 50pF | 4.5                 | -    | 12  | 15            | 18             | ns    |
| Input Capacitance                             | C <sub>I</sub>                      | -                     | -                   | -    | 10  | 10            | 10             | pF    |
| Three-State Output Capacitance                | C <sub>O</sub>                      | -                     | -                   | -    | 20  | 20            | 20             | pF    |
| Power Dissipation Capacitance (Notes 3, 4)    | C <sub>PD</sub>                     | -                     | 5                   | 91   | -   | -             | -              | pF    |

### NOTES:

- $C_{PD}$  is used to determine the dynamic power consumption, per channel.
- $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = Input Frequency,  $f_O$  = Output Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

## Test Circuits and Waveforms

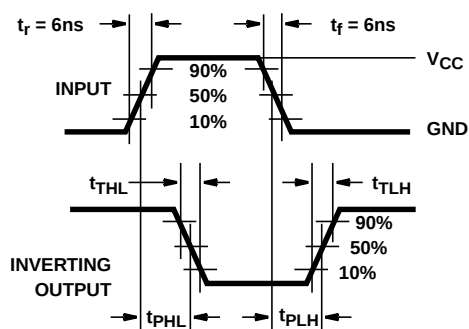


FIGURE 1. HC AND HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

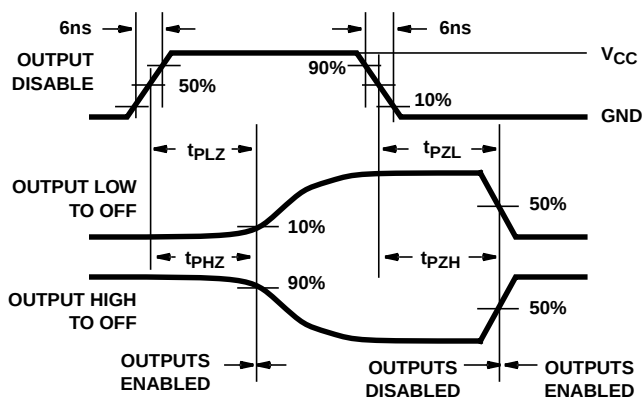


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

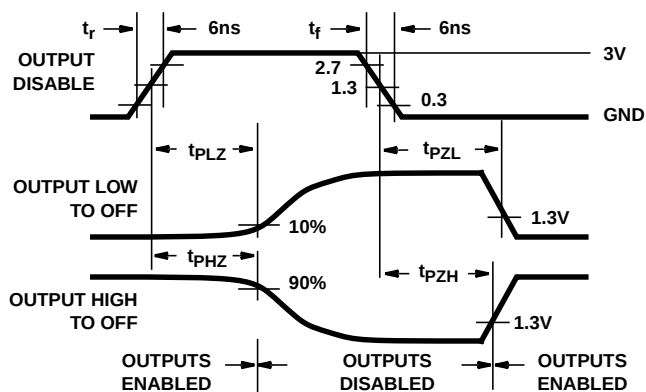
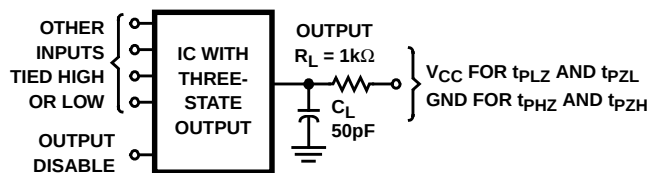


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1k\Omega$  to  $V_{CC}$ ,  $C_L = 50pF$ .

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

**PACKAGING INFORMATION**

| Orderable Device | Status <sup>(1)</sup> | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|
| 8409001CA        | ACTIVE                | CDIP         | J               | 14   | 1           | TBD                     | Call TI          | N / A for Pkg Type           |
| CD54HC243F       | ACTIVE                | CDIP         | J               | 14   | 1           | TBD                     | Call TI          | N / A for Pkg Type           |
| CD54HC243F3A     | ACTIVE                | CDIP         | J               | 14   | 1           | TBD                     | Call TI          | N / A for Pkg Type           |
| CD54HCT243F3A    | ACTIVE                | CDIP         | J               | 14   | 1           | TBD                     | Call TI          | N / A for Pkg Type           |
| CD74HC243E       | ACTIVE                | PDIP         | N               | 14   | 25          | Pb-Free (RoHS)          | CU NIPDAU        | N / A for Pkg Type           |
| CD74HC243EE4     | ACTIVE                | PDIP         | N               | 14   | 25          | Pb-Free (RoHS)          | CU NIPDAU        | N / A for Pkg Type           |
| CD74HC243M       | ACTIVE                | SOIC         | D               | 14   | 50          | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HC243M96     | ACTIVE                | SOIC         | D               | 14   | 2500        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HC243M96E4   | ACTIVE                | SOIC         | D               | 14   | 2500        | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HC243ME4     | ACTIVE                | SOIC         | D               | 14   | 50          | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HC243MT      | ACTIVE                | SOIC         | D               | 14   | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HC243MTE4    | ACTIVE                | SOIC         | D               | 14   | 250         | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HCT243E      | ACTIVE                | PDIP         | N               | 14   | 25          | Pb-Free (RoHS)          | CU NIPDAU        | N / A for Pkg Type           |
| CD74HCT243EE4    | ACTIVE                | PDIP         | N               | 14   | 25          | Pb-Free (RoHS)          | CU NIPDAU        | N / A for Pkg Type           |
| CD74HCT243M      | ACTIVE                | SOIC         | D               | 14   | 50          | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |
| CD74HCT243ME4    | ACTIVE                | SOIC         | D               | 14   | 50          | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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J (R-GDIP-T\*\*)

14 LEADS SHOWN

# CERAMIC DUAL IN-LINE PACKAGE



| PINS **<br>DIM | 14                     | 16                     | 18                     | 20                     |
|----------------|------------------------|------------------------|------------------------|------------------------|
| A              | 0.300<br>(7,62)<br>BSC | 0.300<br>(7,62)<br>BSC | 0.300<br>(7,62)<br>BSC | 0.300<br>(7,62)<br>BSC |
| B MAX          | 0.785<br>(19,94)       | .840<br>(21,34)        | 0.960<br>(24,38)       | 1.060<br>(26,92)       |
| B MIN          | —                      | —                      | —                      | —                      |
| C MAX          | 0.300<br>(7,62)        | 0.300<br>(7,62)        | 0.310<br>(7,87)        | 0.300<br>(7,62)        |
| C MIN          | 0.245<br>(6,22)        | 0.245<br>(6,22)        | 0.220<br>(5,59)        | 0.245<br>(6,22)        |



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. This package is hermetically sealed with a ceramic lid using glass frit.
  - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
  - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

16 PINS SHOWN

## PLASTIC DUAL-IN-LINE PACKAGE



| PINS **             | 14               | 16               | 18               | 20               |
|---------------------|------------------|------------------|------------------|------------------|
| DIM                 |                  |                  |                  |                  |
| A MAX               | 0.775<br>(19,69) | 0.775<br>(19,69) | 0.920<br>(23,37) | 1.060<br>(26,92) |
| A MIN               | 0.745<br>(18,92) | 0.745<br>(18,92) | 0.850<br>(21,59) | 0.940<br>(23,88) |
| MS-001<br>VARIATION | AA               | BB               | AC               | AD               |



4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - The 20 pin end lead shoulder width is a vendor option, either half or full width.

## D (R-PDSO-G14)

## PLASTIC SMALL-OUTLINE PACKAGE



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